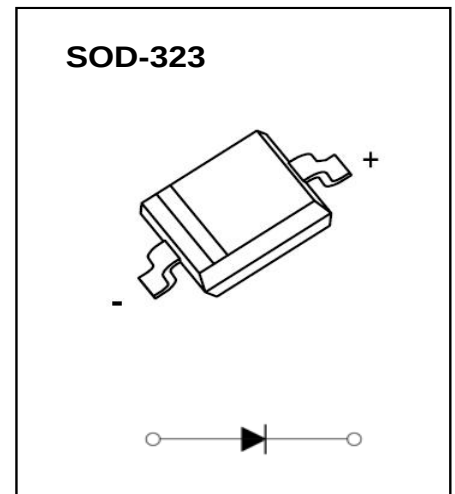
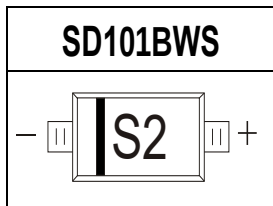


SOD-323 Plastic-Encapsulate Diodes**SD101BWS**

SCHOTTKY BARRIER DIODE

FEATURES

- Low Forward Voltage Drop
- Low Capacitance
- Negligible Reverse Recovery Time

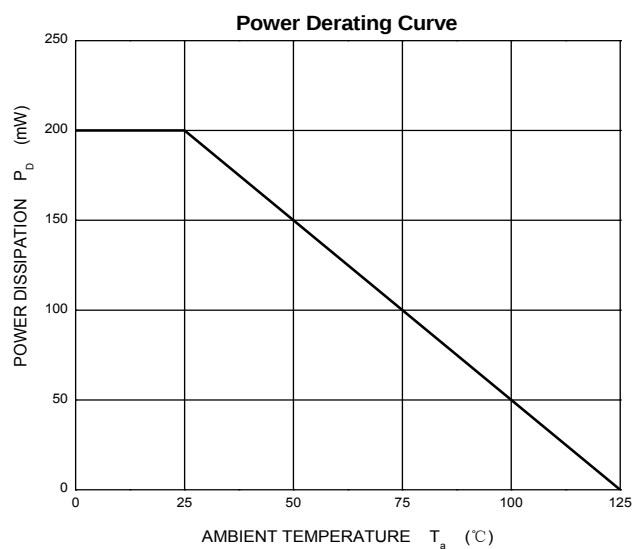
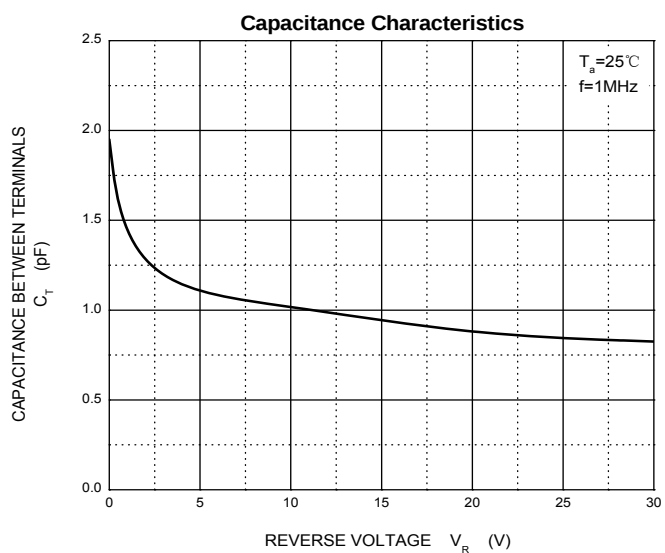
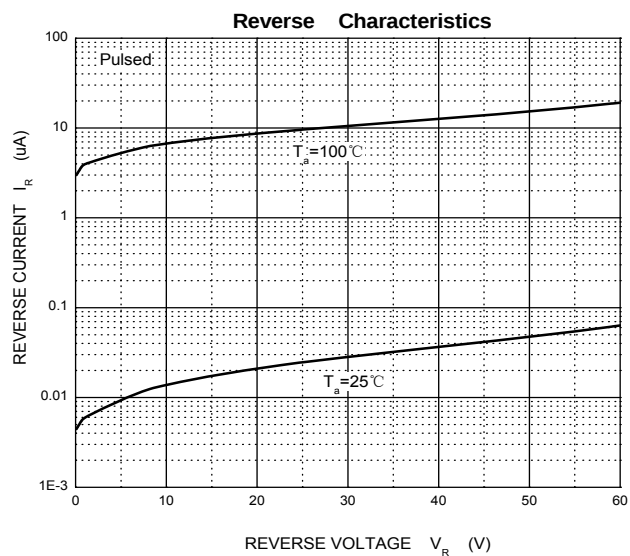
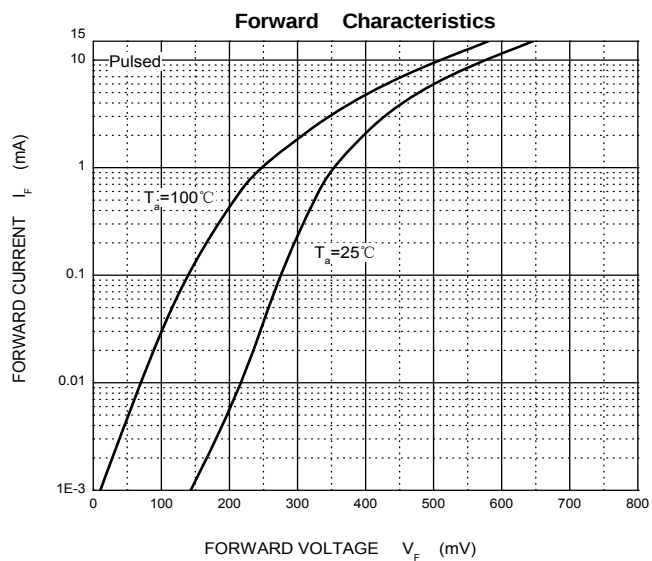
MARKING**MAXIMUM RATINGS** ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	50	V
V_{RWM}	Working Peak Reverse Voltage		
V_R	DC Blocking Voltage		
$V_{R(RMS)}$	RMS Reverse Voltage	35	V
I_{FM}	Forward Continuous Current	15	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$	2	A
P_D	Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	500	$^{\circ}\text{C/W}$
T_j	Operating Junction Temperature Range	-40 ~ +125	$^{\circ}\text{C}$
T_{stg}	Storage Temperature Range	-55 ~ +150	$^{\circ}\text{C}$

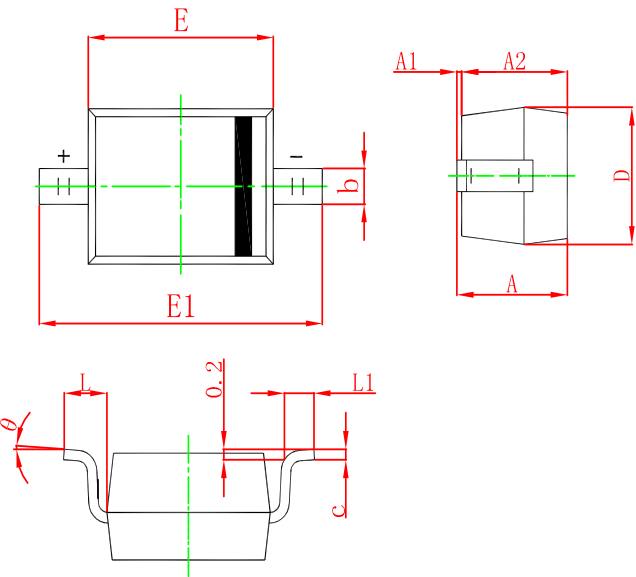
ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=10\mu\text{A}$	50			V
Reverse current	I_R	$V_R=40\text{V}$			0.2	μA
Forward voltage	V_F	$I_F=1\text{mA}$			0.40	V
		$I_F=15\text{mA}$			0.95	
Total capacitance	C_{tot}	$V_R=0\text{V}, f=1\text{MHz}$			2.1	pF
Reverse recovery time	t_{rr}	$I_F=I_R=5\text{mA}, I_{rr}=0.1\times I_R, R_L=100\Omega$			1	ns

Typical Characteristics

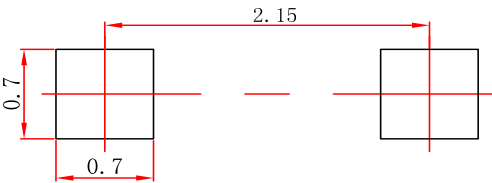


Package Outline Dimensions (SOD-323)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A		1.100		0.043
A1	0.000	0.100	0.000	0.004
A2	0.800	1.000	0.031	0.039
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.500	2.750	0.098	0.108
L	0.475 REF		0.019 REF	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

Suggested Pad Layout (SOD-323)



- Note:
- 1.Controlling dimension:in millimeters.
 - 2.General tolerance:± 0.05mm.
 - 3.The pad layout is for reference purposes only.